

Silicon Bidirectional Switches

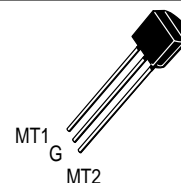
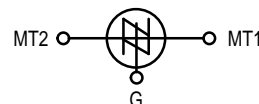
Diode Thyristors

... designed for full-wave triggering in Triac phase control circuits, half-wave SCR triggering application and as voltage level detectors. Supplied in an inexpensive plastic TO-226AA package for high-volume requirements, this low-cost plastic package is readily adaptable for use in automatic insertion equipment.

- Low Switching Voltage — 8 Volts Typical
- Uniform Characteristics in Each Direction
- Low On-State Voltage — 1.7 Volts Maximum
- Low Off-State Current — 0.1 μ A Maximum
- Low Temperature Coefficient — 0.02 %/°C Typical

MBS4991
MBS4992
MBS4993

SBS
(PLASTIC)



CASE 29-04
(TO-226AA)
STYLE 12

MAXIMUM RATINGS ($T_J = 25^\circ\text{C}$ unless otherwise noted.)

Rating	Symbol	Value	Unit
Power Dissipation	P_D	500	mW
DC Forward Current	I_F	200	mA
DC Gate Current (Off-State Only)	$I_{G(\text{off})}$	5	mA
Repetitive Peak Forward Current (1% Duty Cycle, 10 μ s Pulse Width, $T_A = 100^\circ\text{C}$)	$I_{FM(\text{rep})}$	2	Amps
Non-repetitive Forward Current (10 μ s Pulse Width, $T_A = 25^\circ\text{C}$)	$I_{FM(\text{nonrep})}$	6	Amps
Operating Junction Temperature Range	T_J	-55 to +125	$^\circ\text{C}$
Storage Temperature Range	T_{stg}	-65 to +150	$^\circ\text{C}$

MBS4991 MBS4992 MBS4993

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted.)

Characteristic		Symbol	Min	Typ	Max	Unit
Switching Voltage	MBS4991 MBS4992, MBS4993	V _S	6 7.5	8 8	10 9	Vdc
Switching Current	MBS4991 MBS4992 MBS4993	I _S	— —	175 90 175	500 120 250	μAdc
Switching Voltage Differential (See Figure 10)	MBS4991 MBS4992, MBS4993	V _{S1} –V _{S2}	— —	0.3 0.1	0.5 0.2	Vdc
Gate Trigger Current (V _F = 5 Vdc, R _L = 1 k ohm)	MBS4992 MBS4993	I _{GF}	— —	— —	100 500	μAdc
Holding Current	MBS4991 MBS4992 MBS4993	I _H	— — —	0.7 0.2 0.3	1.5 0.5 0.75	mAdc
Off-State Blocking Current (V _F = 5 Vdc, T _A = 25°C) (V _F = 5 Vdc, T _A = 85°C) (V _F = 5 Vdc, T _A = 25°C) (V _F = 5 Vdc, T _A = 100°C)	MBS4991 MBS4991 MBS4992, MBS4993 MBS4992, MBS4993	I _B	— — — —	0.08 2 0.08 6	1 10 0.1 10	μAdc
Forward On-State Voltage (I _F = 175 mAdc) (I _F = 200 mAdc)	MBS4991 MBS4992, MBS4993	V _F	— —	1.4 1.5	1.7 1.7	Vdc
Peak Output Voltage (C _C = 0.1 μF, R _L = 20 ohms, (Figure 7)		V _O	3.5	4.8	—	Vdc
Turn-On Time (Figure 8)		t _{on}	—	1	—	μs
Turn-Off Time (Figure 9)		t _{off}	—	30	—	μs
Temperature Coefficient of Switching Voltage (–50 to +125°C)		T _C	—	+0.02	—	%/°C
Switching Current Differential (See Figure 10)		I _{S1} –I _{S2}	—	—	100	μA

TYPICAL ELECTRICAL CHARACTERISTICS

FIGURE 1 – SWITCHING VOLTAGE versus TEMPERATURE

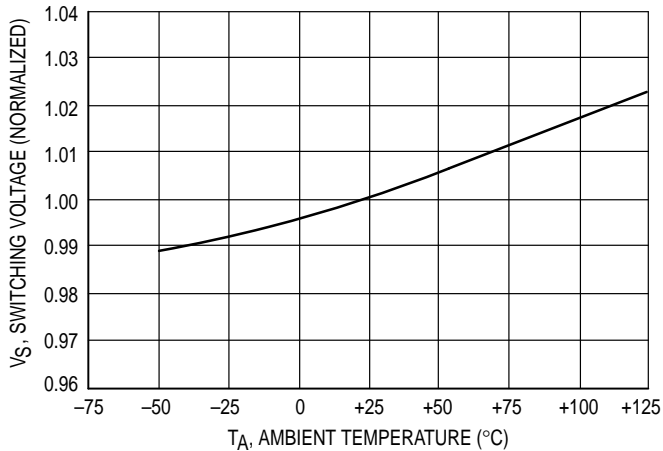


FIGURE 2 – SWITCHING CURRENT versus TEMPERATURE

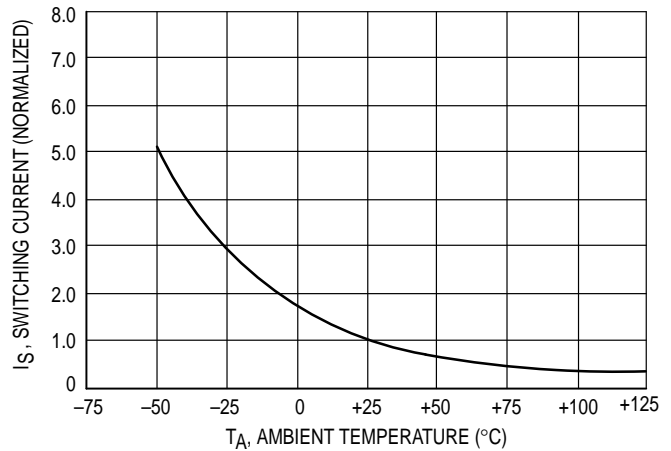


FIGURE 3 – HOLDING CURRENT versus TEMPERATURE

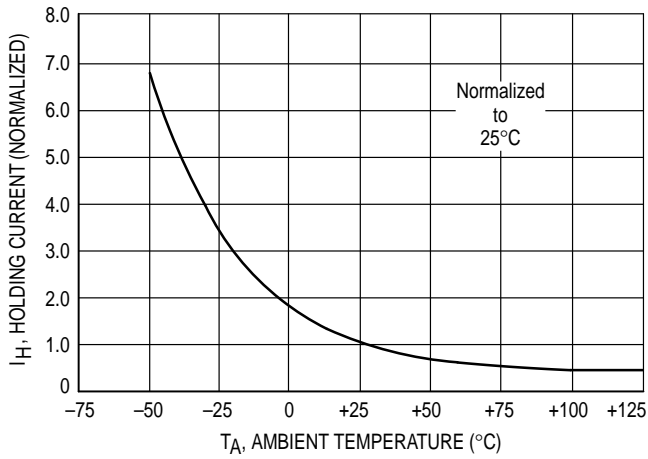


FIGURE 4 – OFF-STATE BLOCKING CURRENT versus TEMPERATURE

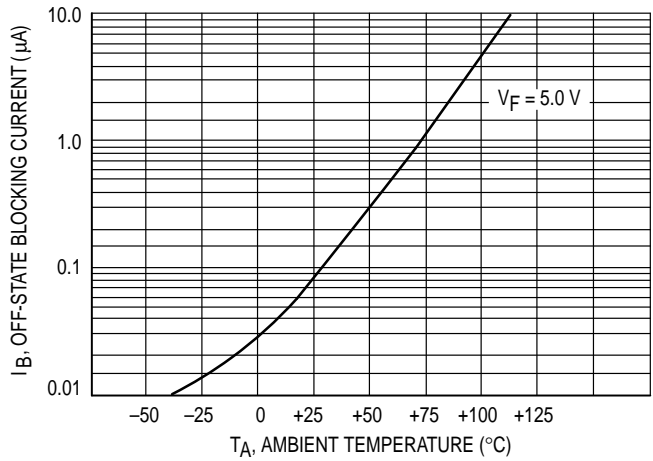


FIGURE 5 – ON-STATE VOLTAGE versus FORWARD CURRENT

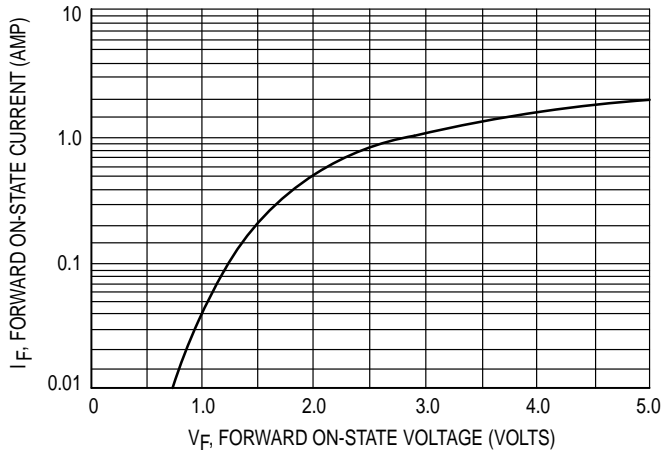


FIGURE 6 – PEAK OUTPUT VOLTAGE (FUNCTION OF R_L AND C_C)

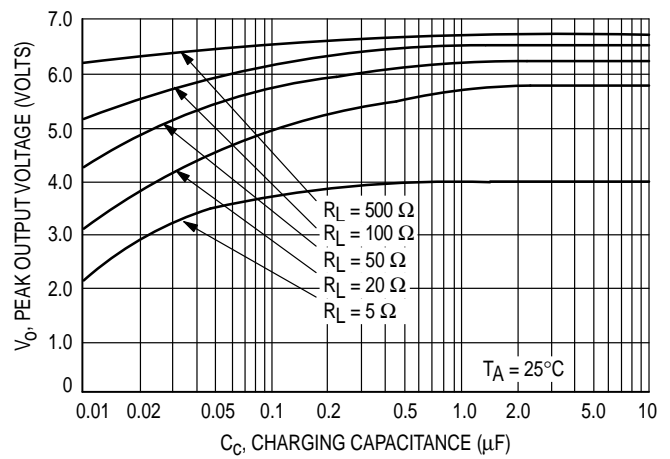


FIGURE 7 – PEAK OUTPUT VOLTAGE TEST CIRCUIT

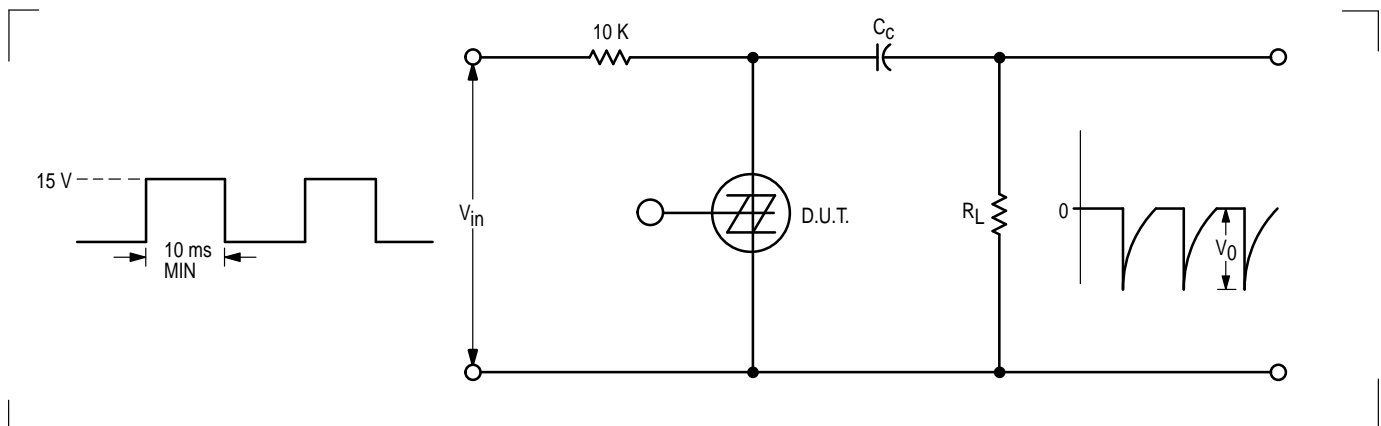
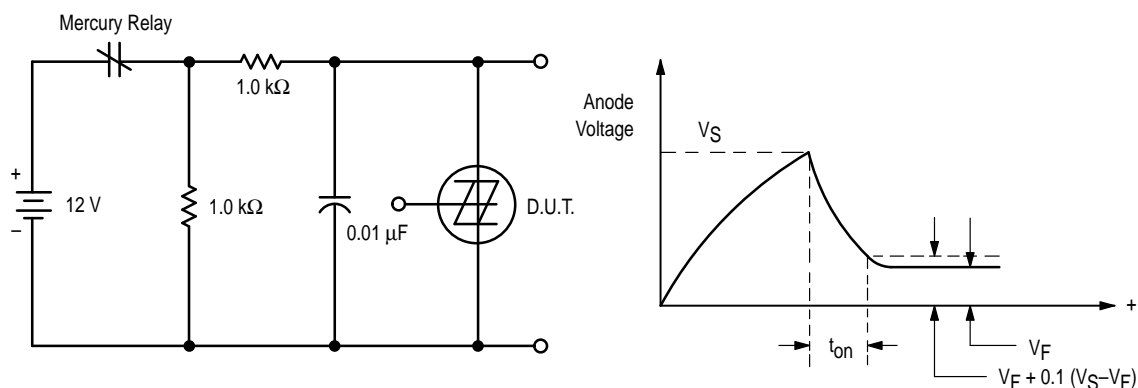
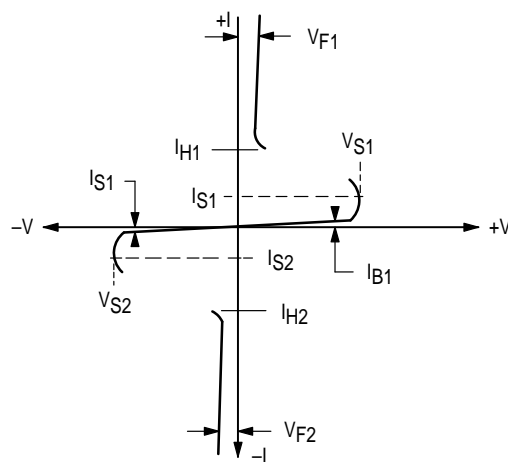
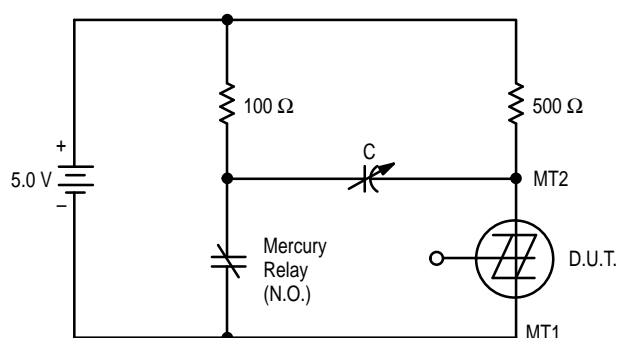


FIGURE 8 – TURN-ON TIME TEST CIRCUIT



Turn-on time is measured from the time V_S is achieved to the time when the anode voltage drops to within 90% of the difference between V_S and V_F .

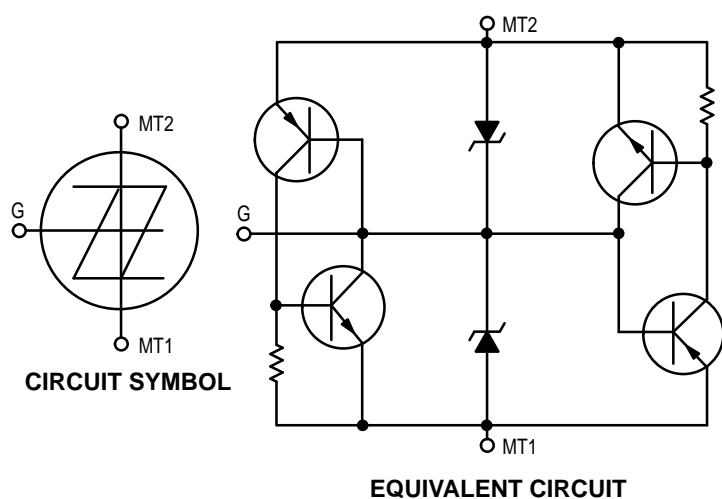
FIGURE 9 – TURN-OFF TIME TEST CIRCUIT



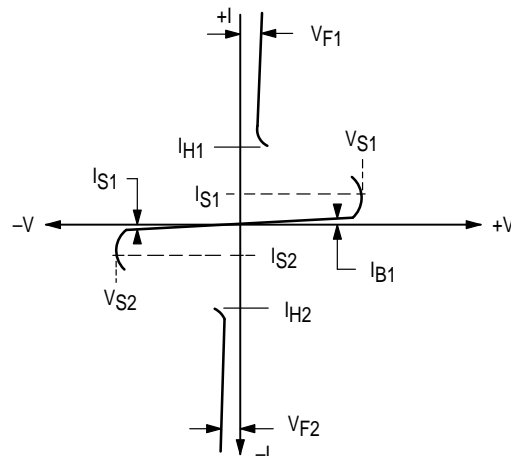
CHARACTERISTICS

With the SBS in conduction and the relay contacts open, close the contacts to cause anode A2 to be driven negative. Decrease C until the SBS just remains off when anode A2 becomes positive. The turn off time, t_{off} , is the time from initial contact closure and until anode A2 voltage reaches zero volts.

FIGURE 10 – DEVICE EQUIVALENT CIRCUIT, CHARACTERISTICS AND SYMBOLS

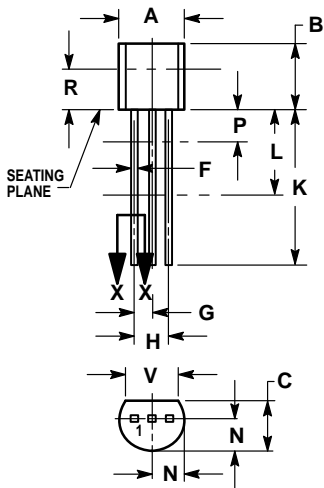


EQUIVALENT CIRCUIT

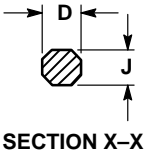


CHARACTERISTICS

PACKAGE DIMENSIONS




STYLE 12:
PIN 1. MAIN TERMINAL 1
2. GATE
3. MAIN TERMINAL 2



- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
 4. DIMENSION F APPLIES BETWEEN P AND L. DIMENSION D AND J APPLY BETWEEN L AND K MINIMUM. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.175	0.205	4.45	5.20
B	0.170	0.210	4.32	5.33
C	0.125	0.165	3.18	4.19
D	0.016	0.022	0.41	0.55
F	0.016	0.019	0.41	0.48
G	0.045	0.055	1.15	1.39
H	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500	—	12.70	—
L	0.250	—	6.35	—
N	0.080	0.105	2.04	2.66
P	—	0.100	—	2.54
R	0.115	—	2.93	—
V	0.135	—	3.43	—

CASE 29-04
(TO-226AA)

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MBS4991/D

